

View Online at <https://aerobasegroup.com/nsn/5961-01-419-4623>

**Inclosure Material:**

Ceramic all semiconductor device diode and metal all semiconductor device diode

**Overall Length:**

0.205 inches all semiconductor device diode and 0.225 inches all semiconductor device diode

**Overall Diameter:**

0.119 inches all semiconductor device diode and 0.124 inches all semiconductor device diode

**End Application:**

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**Component Function Relationship:**

Matched

**Component Name And Quantity:**

4 semiconductor device diode

**Mounting Method:**

Press fit all semiconductor device diode

**Field Force Effect Type:**

Electrostatic charge

**Semiconductor Material:**

Silicon all semiconductor device diode

**Voltage Rating In Volts Per Characteristic:**

35.0 breakdown voltage, dc all semiconductor device diode

**Maximum Operating Temperature Per Measurement Point:**

150.0 degrees celsius junction all semiconductor device diode

**Test Data Document:**

13499-952-6557-001 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

**Terminal Type And Quantity:**

2 case all semiconductor device diode

**Specification Data:**

13499-353-3793 manufacturers specification

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

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